NSN 5961-00-086-0175

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-086-0175 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Germanium **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 40.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 150.00 milliamperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 80131-release1888 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No